MAX706RxxA Rev. A

RELIABILITY REPORT

FOR

MAX706RxxA

PLASTIC ENCAPSULATED DEVICES

July 17, 2006

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

/en

Jim Pedicord Quality Assurance Manager, Reliability Operations

Conclusion

The MAX706R successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX706R microprocessor (μ P) supervisory circuit reduces the complexity and number of components required to monitor +3V power-supply levels in +3V to +5V μ P systems. This device significantly improves system reliability and accuracy compared to separate ICs or discrete components.

The MAX706R supervisory circuit provides the following four functions:

- 1) A reset output during power-up, power-down, and brownout conditions.
- 2) An independent watchdog output that goes low if the watchdog input has not been toggled within 1.6s.

3) A 1.25V threshold detector for power-fail warning, low-battery detection, or for monitoring a power supply other than the main supply.

4) An active-low, manual-reset input.

The MAX706R reset-threshold voltage level is 2.63V. It has active-low reset output signals.

The MAX708R/S/T provide the same functions as the MAX706R/S/T and MAX706AR/AS/AT except they do not have a watchdog timer. Instead, they provide both RESET-bar and RESET outputs. As with the MAX706, devices with R, S, and T suffixes have reset thresholds of 2.63V, 2.93V, and 3.08V, respectively.

This device is available in 8-pin SO, DIP, and µMAX® packages and is fully specified over the operating temperature range.

B. Absolute Maximum Ratings

Terminal Voltage (with respect to GND) VCC-0.3V to +6VAll Other Inputs (Note 1)-0.3V to (VCC + 0.3V)Input Current20mAVCC20mAGND20mAOutput Current (all outputs)20mAContinuous Power Dissipation (TA = +70°C)22mA8-Pin PDIP (derate 9.1mW/°C above +70°C)727.3mW8-Pin sO (derate 5.9mW/°C above +70°C)362mWOperating Temperature Range0°C to +70°CMAX70_C0°C to +70°CMAX70_E-40°C to +85°CMAX70_M-55°C to +125°CJunction Temperature+150°CStorage Temperature Range-65°C to +150°CLead Temperature (soldering, 10s)+300°C	Item	Rating
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8-Pin PDIP (derate 9.1mW/°C above +70°C)727.3mW8-Pin SO (derate 5.9mW/°C above +70°C)470.6mW8-Pin µMAX (derate 4.5mW/°C above +70°C)362mWOperating Temperature Range0°C to +70°CMAX70_C0°C to +70°CMAX70_E-40°C to +85°CMAX70_M-55°C to +125°CJunction Temperature+150°CStorage Temperature Range-65°C to +150°C	Output Current (all outputs)	20mA
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MAX70_M-55°C to +125°CJunction Temperature+150°CStorage Temperature Range-65°C to +150°C		0°C to +70°C
Junction Temperature+150°CStorage Temperature Range-65°C to +150°C	MAX70 E	-40°C to +85°C
Storage Temperature Range -65°C to +150°C	MAX70 [–] M	-55°C to +125°C
Storage Temperature Range -65°C to +150°C	Junction Temperature	+150°C
	•	-65°C to +150°C
		+300°C

II. Manufacturing Information

A. Description/Function:	+3V Voltage Monitoring, Low-Cost μP Supervisory Circuits
B. Process:	S3 - Standard 3 micron silicon gate CMOS
C. Number of Device Transistors:	572
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Malaysia, Philippines, or Thailand
F. Date of Initial Production:	July, 1992

III. Packaging Information

A. Package Type:	8-pin µMAX	8-pin SO	8-pin PDIP
B. Lead Frame:	Copper	Copper	Copper
C. Lead Finish:	Solder Plate of	or 100% Matte Tin (all pa	ackages)
D. Die Attach:	Silver-filled Epoxy	Silver-filled Epoxy	Silver-filled Epoxy
E. Bondwire:	Gold (1.3 mil dia.)	Gold (1 mil dia.)	Gold (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	# 05-1701-0164	# 05-1701-0101	# 05-1701-100
H. Flammability Rating:	Class UL94-V0	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C:	Level 1	Level 1	Level 1

IV. Die Information

A. Dimensions:	70 x 65 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	3 microns (as drawn)
F. Minimum Metal Spacing:	3 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord Bryan Preeshl (Manager, Reliability Operations) (Managing Director of QA)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \text{ x } 4340 \text{ x } 160 \text{ x } 2} \text{(Chi square value for MTTF upper limit)}$ Temperature Acceleration factor assuming an activation energy of 0.8eV

 $\lambda = 6.87 \times 10^{-9}$ $\lambda = 6.87 \text{ F.I.T.}$ (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5934) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1N**). Current monitor data for the S3 Process results in a FIT Rate of 0.15 @ 25C and 2.60 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The PW27-4 die type has been found to have all pins able to withstand a transient pulse of \pm 1000V per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of \pm 100mA.

Table 1 Reliability Evaluation Test Results

MAX706RxxA

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	(Note 1)				
	Ta = 150°C Biased Time = 192 hrs.	DC Parameters & functionality		160	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	µMAX PDIP SO	77 77 77	0 0 0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)		
1.	All pins except V _{PS1} <u>3/</u>	All V _{PS1} pins		
2.	All input and output pins	All other input-output pins		

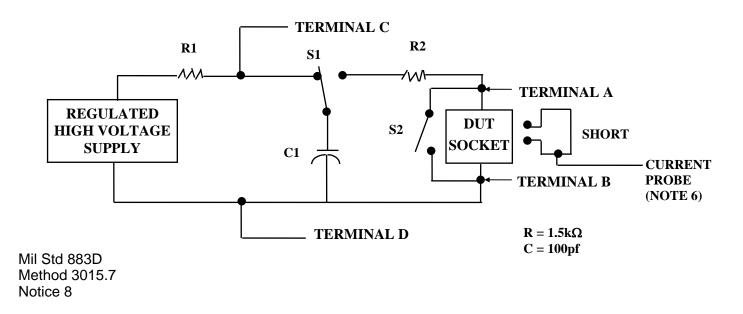
TABLE II. Pin combination to be tested. 1/2/

- 1/ Table II is restated in narrative form in 3.4 below.
- $\frac{32}{2}$ No connects are not to be tested. $\frac{32}{2}$ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_S$, $-V_S$, V_{RFF} , etc).

3.4 Pin combinations to be tested.

- Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- Each input and each output individually connected to terminal A with respect to a combination of C. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



PKG. CODE: S8-2		SIGNATURES	DATE	CONFIDENTIAL & PROPRI	IETARY
CAV./PAD SIZE: 90 X 9	PKG. DESIGN			BOND DIAGRAM #: 05-1701-0101	REV: B

